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U.S. PATENT DOCUMENTS						
Examiner Initial*	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

FOREIGN PATENT DOCUMENTS							
	Document Number	Date	Country	Class	Subclass	Translation	
						Yes	No
						Abs.	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)	
SWT	Fujii, M., Hayashi, S., Yamamoto, K., "Photoluminescence from B-Doped Si Nanocrystals," Journal of Applied Physics, American Institute of Physics, New York, Vol. 83, No. 12, June 15, 1998, pp. 7953-7957.
SWT	Levoska, J., Tyunina, M., Leppävuori, S., "Laser Ablation Deposition of Silicon Nanostructures," NanoStructured Materials, Elsevier, New York, Published Online October 6, 1999, pp. 101-106.
SWC	Brus, L., "Luminescence of Silicon Nanocrystals and Porous Silicon," Japanese Journal of Applied Physics, Publication Office Japanese Journal of Applied Physics, Tokyo, JP, Vol. 34, No. 34-1, Suppl., January 1994, pp. 5-7.

Examiner	CRANE	Date Considered	6/2005
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			